Sheet: 1 of: 1

	184°)	
U.S. DEPARTMENT OF COMMERCE	Atty Docket No:	Serial No:
PATENT AND TRADEMARK OFFICE	94-0302.02	09/654,093
	Applicant:	
ISCLOSURE STATEMENT BY APPLICANT	Thakur et al.	
	Filing Date:	Group:
(use several sheets if necessary)	8/31/00	-
	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE ISCLOSURE STATEMENT BY APPLICANT	U.S. DEPARTMENT OF COMMERCE Atty Docket No: PATENT AND TRADEMARK OFFICE 94-0302.02 Applicant: Thakur et al. Filing Date:

U.S. PATENT DOCUMENTS

Examiner		Document				
Initial		Number	Date	Name	Class	Subclass
PIBE	AA	6,033,979	03/07/00	Endo	438	622
PSBL	AC	5,585,308	12/17/96	Sardella	437	190
PE-BA	AD	5,552,343	09/03/96	Hsu	437	195
PEBB	AE	5,531,183	07/02/96	Sivaramakrishnam et al.	117	093
PEBB	AF	5,474,955	12/12/95	Thakur	437	173
38B	AG	5,399,532	03/21/95	Lee et al.	437	228
REBR	AH	5,384,288	01/24/95	Ying	437	228
CEB1	Al	5,372,974	12/13/94	Doan et al.	437	240
PS BA	AJ	5,260,232	11/09/93	Muroyama et al.	437	187
Q5 (3) W	AK	5,236,862	08/17/93	Pfiester et al.	437	070
6580	AL	5,196,907	03/23/93	Birkle et al.	257	289
6,00	AM	5,166,088	11/24/92	Ueda et al.	437	047
P5 B12	AN	5,164,330	11/17/92	Davis et al.	437	192
PS BP	AO	5,077,238	12/31/91	Fujii et al.	437	228
CEBO	AP	4,992,840	02/12/91	Haddad et al.	357	23.15
.C5 BM	AQ	4,917,759	04/17/90	Fisher et al.	156	643
P5 B12	AR	4,879,257	11/07/89	Patrick	437	195
PEBB	AS	4,849,797	07/18/89	Ukai et al.	357	237
P& BID	AT	4,824,802	04/25/89	Brown et al.	437	192
C5 BSC	AU	4,708,767	11/24/87	Bril	437	018
PE 97	AV	3,925,572	12/09/75	Naber	427	087

FOREIGN PATENT DOCUMENTS

Examiner		Document					I rans	lation
Initial		Number	Date	Country	Class	Subclass	Yes	No
	AX	04-326732	11/16/92	Japan	H01L-021	316		\boxtimes
	AY	04-067632	03/03/92	Japan	H01L-021	3205		
	ΑZ	03-280543	12/11/91	Japan	H01L-021	3205		
	BA	01-047055	02/21/89	Japan	H01L-021	90		

Initial		OTHER ART (including author, title, date, pertinent pages, etc.)
	ВВ	S. Wolf, "Silicon Processing for the VLSI Era", Vol. II, pp. 45, 51, 194-99, 370, 382, 387-88, June, 1990
	BC	Butler, John, Greg Allen, Anthony Hall, and Romuald Nowak, "Electrical Characterization of Doped and Undoped PECVD TEOS Oxides", presented at VMIC, June 1990.

Examiner:	and	-[8	rock	Date Considered:	1/	18	1/2001
	 				$\overline{}$	-	